

Code: 5G364

UNIT-IV

7. Sketch the following signals:

$$x_1(n) = n, n > 0$$

= 0 otherwise

$$x_2(n) = n^2, n > 0$$

= 0 otherwise

Also sketch decimator and interpolated version of above systems with a factor of '2'.

14M

OR

8. a) Explain multistage implementation of sampling rate conversion.

b) Summarize the advantages of multirate signal processing.

4M

UNIT-V

9. a) How non-stationary signals are analyzed with the help of DFT?

7M

b) Discuss about musical sound processing.

7M

OR

10. a) Explain the process of signal compression and decompression

7M

b) Discuss about oversampling of A/D Converter

7M

H	lall 7	Ticket Number :	
Со	de:	5G365	
		III B.Tech. II Semester Supplementary Examinations Nov/Dec 2019 Electronic Measurements and Instrumentation (Electronics and Communication Engineering)	9
I		. Marks: 70 Answer all five units by choosing one question from each unit ($5 \times 14 = 70 \text{ Mar}$ *****	
1.	a)	What is effect of loading on DC voltmeter?	4M
	b)	It is desired to measure the voltage across the 100K resistor in the circuit given below figure. Two voltmeters are available for this measurement. Voltmeter1 with a sensitivity of 1K /V and voltmeter2 with a sensitivity of 20K /V. Both meters are used on their 50V range.	
		200 ΚΩ	
		150V \\ \geq 100 KO \(\frac{1}{V}\)	
		150V ∮- §100 KΩ (V)	
			10M
		OR	
2.	a)	Explain about the construction and principle of operation of PMMC instrument.	10M
	b)	Write advantages of PMMC instrument.	4M
3.	a)	UNIT-II Explain the principle and working of Spectrum analyser with necessary block	
, .	u)	diagram.	7M
	b)	Write the differences between wave analyzer and harmonic distortion analyzer.	7M
	,	OR .	01.4
1.	a)	Explain the construction of Heterodyne wave analyzer.	9M
	b)	What is meant by distortion? Mention few types of harmonic distortion caused by an electronic amplifier.	5M
		UNIT-III	
5.	a)	Explain the operation of Digital Storage oscilloscope with necessary diagrams.	9M
	b)	In a CRT, anode to cathode voltage is 2000V. The parallel deflector plates are	
		1.5cm long and spaced 5mm. The screen is 50cm from the centre of deflection plates. Find the deflection sensitivity of the CRT.	5M
		OR	JIVI
S .	a)	Draw and explain the horizontal deflection system in a CRO.	10M
	b)	What is the significance of time base generator in CRO.	4M
_		UNIT-IV Draw the circuit of Wein bridge and derive the expression for frequency?	
7.	a)	Draw the circuit of Wein bridge and derive the expression for frequency? Determine equivalent parallel resistance and capacitance that causes a Wein	8M
	b)	Determine equivalent parallel resistance and capacitance that causes a Wein bridge to balance with the following component values: R1=2.7K , C1=5 μ F, R2=22K , R4=100K . The operating frequency is 2.2KHz?	6M
3.	a)	Explain the working of Wheatstone bridge and derive the equation for balance condition and unbalance condition.	10M
	b)	What are the errors made in the measurement of resistance using Wheatstone bridge?	4M
,	-1	UNIT-V	01.4
).	a)	What is transducer? Write in detail the classification of transducers.	6M
	b)	What is force? Explain how stain gauges can be used for measurement of force. OR	8M
).	a)	What is the need of data acquisition system? Explain DAS with necessary diagram.	7M

b) Where is strip chart recorder used? Explain the functionality with diagrams.

7M

Code: 5G363						R-15
Hall Ticket Number:						

III B.Tech. II Semester Supplementary Examinations Nov/Dec 2019 Microprocessors and Interfacina (Electronics and Communication Engineering) Max. Marks: 70 Time: 3 Hours Answer all five units by choosing one question from each unit ($5 \times 14 = 70$ Marks) UNIT-I Draw the architecture of 8086 microprocessor and explain the functionality of 1. a) each unit in detail. 7M With examples, explain how multiplexing is implemented in 8086 7M b) OR a) List out the flag bits in the Flag register of 8086 and describe the functionality of 2. each flag bit. 6M Explain the following 8086 instructions with examples (i) MUL, (ii) IMUL, (iii) DIV, (iv) IDIV 8M UNIT-II 3. Interface a 12 bit DAC with 8255 and write a program to generate a triangular waveform of period 10 ms. The CPU runs at 5 MHz clock frequency. 7M What do you mean by a DMA data transfer? Explain the implementation in 8086 system using 8257/8237 DMA controller. 7M Draw a block diagram to interface two 16K X 8 SRAM (62128) to the 16-bit data bus of 8086 based system. Design the address decoder for the address range from 00000H - 07FFFFH for both the SRAMs. 10M b) How DRAM's are different from SRAM's? Why DRAMs are said to employ address multiplexing? 4M UNIT-III What are the advantages of using 8259? Draw and explain the interfacing of 5. a) cascaded 8259s with 8086. 7M Explain the significance of different bits of control word register format of 8253 b) PIT/PIC. 7M OR 7M 6. a) Explain the interrupt acknowledgement sequence of 8086 with timing diagram Draw the interrupt vector table 0f 8086. Explain the maskable and non-maskable b) interrupts 7M **UNIT-IV** a) Describe the Asynchronous transmission and reception schemes of 8251 in detail 7. 7M Draw the block diagram of 8251 and explain each block. 7M Draw the flowchart showing how synchronous serial data can be sent from a port line of 8251 using software routine. 7M Discuss about the various serial communication standards for data transmission 7M b) UNIT-V Compare and contrast the salient features of 80286 and 80386 6M 9. a) Discuss the register organisation of 80286 b) 8M 10. a) Discuss about real and protected mode of 80386. 6M What is paging? Draw the block diagrammatic representation of complete 80386 paging mechanism. 8M

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		III B.Tech. II Seme		olemer Owave	•			ons Nov,	/Dec 2019	
		(Elec	ctronics &		_		_	eerina)		
	_	x. Marks: 70 Answer all five units by							Time: 3 Hours 4 = 70 Marks)	
				UN	IIT–I					
1.	a)	Differentiate between TI	E & TM mod	les in Re	ctangu	lar wa	veguide	with its ph	ysical significance.	
	b)	Write short note on Mic	cro strip and	d Strip Tr		ssion	lines.			
2.	a)	Derive the expressions	for Ev & Hv	compone	OR	der TN	1 modes	s in rectand	rular waveguide	
۷.	,	A TE ₁₀ mode is propag		·						
	b)	Determine Cut off frequ	•	•	•	•				
		frequency.	•			•		J	G	
				UN	IIT–II					
3.	a)	An air filled circular wa	•	•			•	•		
		dimension such that fc and Phase velocity.	= 0.8 f for c	iominant	mode	, Dete	rmine L	Diameter o	f guide, wavelength	
	b)	Explain Circular wave	nuide impor	tance ar	nd deri	ve its i	charact	eristics ea	uation	
	D)	Explain Onodial wave	galae IIIIpol	tarioo ar	OR	VO 110	onaraot	01101100 09	dation.	
4.	a)	Derive an expression f	or E & H co	mponen	ts of re	ectang	ular ca	vity resona	itor.	
	b)	Define the Q-factor of re	sonator and	d obtain e	express	sion fo	Q of R	ectangular	cavity resonator.	
				UN	IT–III					
5.	a)	What is working princip	ole of Ferrite	e Device	s and I	Farada	ay rotat	ion in Micr	owave devices?	
	b)	Derive S Matrix of a Di	rectional Co	oupler.						
6.	۵)	Show using S matrix th	oory that a	loce non	OR region	ocal ti	vo port	microwov	a dovices cannot be	
Ο.	a)	constructed.	eory mar a	1055 11011	-recipi	ocai ii	vo port	IIICIOWave	e devices carriot be	
	b)	The Incident power in a	a directional	coupler	is 520	mW.	If the po	ower in an	auxiliary arm is 325	
	,	micro W. Calculate cou		•			•		,	
				UN	IT–IV					
7.	a)	Discuss the working p aid of schematic diagra	•	Reflex KI	ystron	with (generat	ion and ar	mplification with the	
	b)	Write a short note on E	ackward W	ave Osc	illator.					
_	,				OR					
8.	a)	Describe the principle of	•				•	•	Mode of Oscillations.	
	b)	How the function of TV	/ I does diff			ction i	n Magr	netron.		
9.	a)	What is TRAPATT diod	te and draw		IT-V ematic	_ diagra	ım with	equivalen	t circuit	
J.	а) b)	Give the mechanism of				alagic	uii VVILII	oquivalell	t on out.	
	IJ,			ao O3011	OR					

Discuss importance of PIN diode at microwave frequencies.

Explain VSWR Measurement using Microwave Test Bench.

10.

7M 7M

Hall ⁻	Ticke	et Number :											
		R-15											
Code		3.Tech. II Semester Supplementary Examinations Nov/Dec 2019 Radar Engineering (Electronics and Communication Engineering)											
		Time: 3 Ho er all five units by choosing one question from each unit ($5 \times 14 = 70$ Marks) ***********************************	urs										
		UNIT-I	10M										
1.	a)												
	b)	What is the peak power and duty cycle of radar whose average transmitter power is 200W, pulse width of 1µs and a pulse repetition frequency of 1000Hz? OR	4M										
2.	a)	What are the different range frequencies that a radar can operate and give their applications?	7M										
	b)	Explain the System losses in radar.	7M										
		UNIT-II											
3.	a)	With the help of a suitable block diagram, explain the operation of a CW Doppler radar in a sideband super heterodyne receiver.											
	b)	Calculate the Doppler frequency of stationary CW radar transmitting at 6 MHz frequency when a moving target approaches the radar with a radial velocity of 100 kmph.	4M										
4	- \	OR											
4.	a)	Describe methods to achieve isolation between transmitter and receiver of a CW Doppler radar if same antenna is to be used for transmission and reception.											
	b)	List out the possible errors for measurement of altitudes accurately using a FM-CW altimeter.											
		UNIT-III											
5.	a)	Explain briefly about coherent MTI radar.	10M										
	b)	Calculate the lowest blind speed of an MTI system operating at 4.2 cm wave length and transmitting at a pulse repetition time of 286 μ S. OR	4M										
6.	a)	Explain the principle and process of binary moving window detector.	7M										
	b)	Write a short note on staggered PRF's.	7M										
		UNIT-IV											
7.	a)	Describe the phase comparison mono pulse tracking technique in a radar system with the help of necessary block diagram.	10M										
	b)	Compare and contrast conical scan and sequential lobing type tracking techniques. OR	4M										
8.	a)	Explain the amplitude comparison mono pulse tracking technique.	8M										
	b)	Why does tracking radar have poor accuracy at low elevation angles? Explain.	6M										
		UNIT-V											
9.	a)	Discuss in detail about Matched-filter Receiver with necessary expressions.	10M										
	b)	A radar receiver is connected to a 50 ohm resistance antenna that has an equivalent noise resistance of 30 ohms. Calculate the noise figure of the receiver											
		and the equivalent noise temperature of the receiver.	4M										
10.	a)	OR Explain various types of radar displays.	7M										
	b)	Write notes on circulators.	7 M										
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Hall Ticket Number:						
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Code: 5G361

III B.Tech. II Semester Supplementary Examinations Nov/Dec 2019

VLSI Design (Electronics and Communication Engineering) Max. Marks: 70 Time: 3 Hours Answer all five units by choosing one question from each unit ($5 \times 14 = 70$ Marks) UNIT-I Explain the MOS Transistor operation with the help of neat sketches in the 1. Enhancement mode 7M List out the processing steps involved in the manufacturing of an IC. 7M b) OR 2. a) Describe in detail about integrated passive components 5M b) Explain CMOS fabrication using N-well process with neat diagrams. 9M UNIT-II Interpret and discuss the limits of scaling. Justify the need of scaling for VLSI circuits? 3. a) 5M Design a layout for CMOS 3-input NOR gate. 9M b) OR 4. Write stick encoding for : i. n diffusion ii. Polysilicon iii. Metal-1 iv. Contact cut 4M a) b) Determine the pull up to pull down ratio of an nMOS inverter driven by another nMOS transistor 10M UNIT-III Explain about the concepts of Sheet Resistance and how its concept is applied to 5. MOS transistors for calculation of sheet resistance 8M Define fan-in and fan-out. Explain their effects on propagation delay. 6M b) OR What do you mean by inverter delay? Explain. 6. a) 6M Explain different switch logic used for designing of VLSI circuits? b) 8M UNIT-IV 7. a) Draw the logic diagram of zero/one detector and explain its operation with the help of stick diagram. 9M Explain about Design Rule Check. Why is it employed? 5M b) Explain the architectural issues of subsystem design 8. 6M a) With the help of a schematic explain the principle of Tree Multiplier. 8M b) **UNIT-V** Explain the concept of design verification and design capture tools used in VHDL 9. a) synthesis. 10M What is Built in self-Test, explain it in detail its objectives 4M OR 10. 8M a) Give the Architecture of a boundary scan test and explain the same b) Write short notes on

(i) Circuit design flow (ii) Circuit synthesis

6M